74LV4052-Q100

Dual 4-channel analog multiplexer/demultiplexer

Rev. 5 — 29 March 2024 Product data sheet

1. General description

The 74LV4052-Q100 is a dual single-pole quad-throw analog switch suitable for use in 4:1 multiplexer/demultiplexer applications. Each switch features four independent inputs/outputs (nY0, nY1, nY2 and nY3) and a common input/output (nZ). A digital enable input ($\overline{E}$) and two digital select inputs (S0, S1) are common to both switches. When $\overline{E}$ is HIGH, the switches are turned off. Digital inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.0 to 6.0 V
- CMOS low power dissipation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Optimized for low-voltage applications: 1.0 V to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low ON resistance:
  - 145 Ω (typical) at V_{CC} - V_{EE} = 2.0 V
  - 90 Ω (typical) at V_{CC} - V_{EE} = 3.0 V
  - 60 Ω (typical) at V_{CC} - V_{EE} = 4.5 V
- Logic level translation:
  - To enable 3 V logic to communicate with ± 3 V analog signals
- Typical 'break before make' built in
- Complies with JEDEC standards:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LV4052D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74LV4052PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

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4. Functional diagram

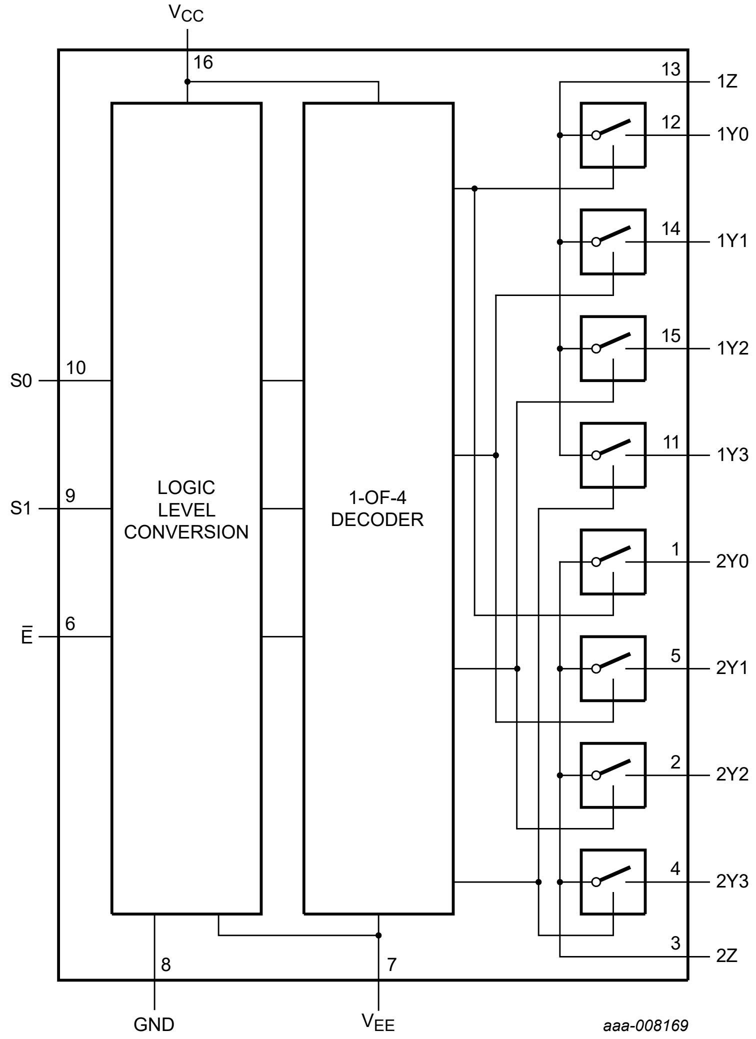


Fig. 1. Functional diagram

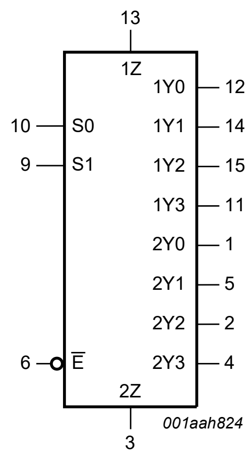


Fig. 2. Logic symbol

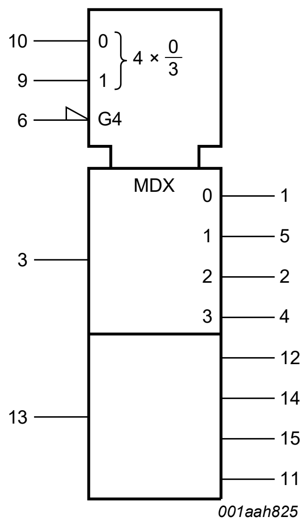


Fig. 3. IEC logic symbol

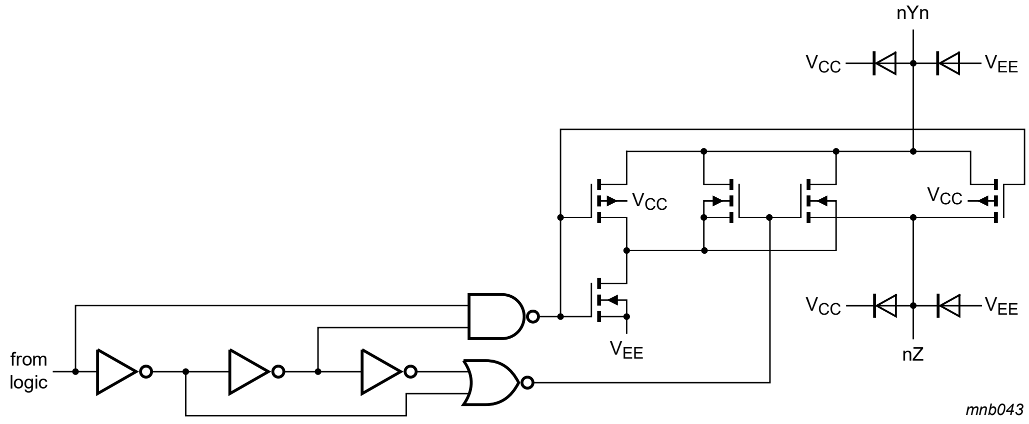
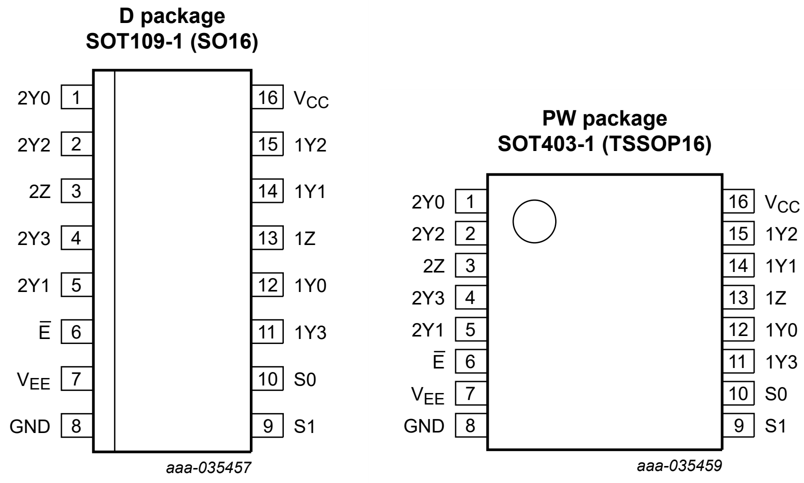


Fig. 4. Schematic diagram (one switch)

5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
2Y0, 2Y1, 2Y2, 2Y3	1, 5, 2, 4	independent input or output
$\overline{E}$	6	enable input (active LOW)
V_{EE}	7	negative supply voltage
GND	8	ground (0 V)
S0, S1	10, 9	select logic input
1Y0, 1Y1, 1Y2, 1Y3	12, 14, 15, 11	independent input or output
1Z, 2Z	13, 3	common input or output
V_{CC}	16	positive supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input			Channel on
$\overline{E}$	S1	S0	
L	L	L	nY0 and nZ
L	L	H	nY1 and nZ
L	H	L	nY2 and nZ
L	H	H	nY3 and nZ
H	X	X	none

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage		[1]	-0.5	+7.0	V
I_{IK}	input clamping current	V_I < -0.5 V or V_I > V_{CC} + 0.5 V	[2]	-	±20	mA
I_{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	[2]	-	±20	mA
I_{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	[2]	-	±25	mA
T_{stg}	storage temperature			-65	+150	°C
P_{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[3]	-	500	mW

[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current flows out of terminals nYn. In this case, there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE}.

[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

[3] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.
For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CC}	supply voltage	see Fig. 5	[1]	1	3.3	6	V
V_I	input voltage			0	-	V_{CC}	V
V_{SW}	switch voltage			0	-	V_{CC}	V
T_{amb}	ambient temperature	in free air		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V_{CC} = 1.0 V to 2.0 V		-	-	500	ns/V
		V_{CC} = 2.0 V to 2.7 V		-	-	200	ns/V
		V_{CC} = 2.7 V to 6.0 V		-	-	100	ns/V

[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to 6.0 V. However, LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).

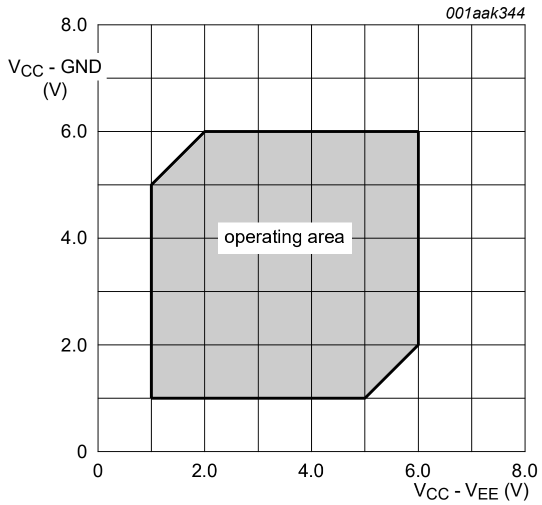


Fig. 5. Guaranteed operating area as a function of the supply voltages

9. Static characteristics

Table 6. Static characteristics

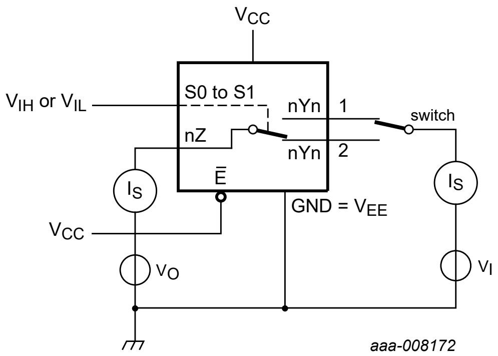
At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V_{CC} = 1.2 V	0.9	-	-	0.9	-	V
		V_{CC} = 2.0 V	1.4	-	-	1.4	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V_{CC} = 4.5 V	3.15	-	-	3.15	-	V
		V_{CC} = 6.0 V	4.20	-	-	4.20	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.2 V	-	-	0.3	-	0.3	V
		V_{CC} = 2.0 V	-	-	0.6	-	0.6	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V_{CC} = 4.5 V	-	-	1.35	-	1.35	V
		V_{CC} = 6.0 V	-	-	1.80	-	1.80	V
I_I	input leakage current	$V_I = V_{CC}$ or GND						
		V_{CC} = 3.6 V	-	-	1.0	-	1.0	μA
		V_{CC} = 6.0 V	-	-	2.0	-	2.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_I = V_{IH}$ or V_{IL}; see Fig. 6						
		V_{CC} = 3.6 V	-	-	1.0	-	1.0	μA
		V_{CC} = 6.0 V	-	-	2.0	-	2.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_I = V_{IH}$ or V_{IL}; see Fig. 7						
		V_{CC} = 3.6 V	-	-	1.0	-	1.0	μA
		V_{CC} = 6.0 V	-	-	2.0	-	2.0	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; I_O = 0 A						
		V_{CC} = 3.6 V	-	-	20	-	40	μA
		V_{CC} = 6.0 V	-	-	40	-	80	μA
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC}$ - 0.6 V; V_{CC} = 2.7 V to 3.6 V	-	-	500	-	850	μA

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
C_I	input capacitance		-	3.5	-	-	-	pF
C_{sw}	switch capacitance	independent pins nYn	-	5	-	-	-	pF
		common pins nZ	-	12	-	-	-	pF

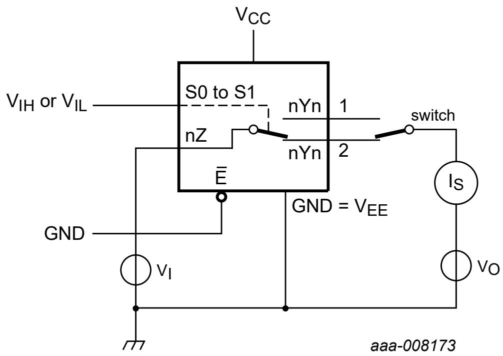
[1] Typical values are measured at T_{amb} = 25 °C.

9.1. Test circuits



V_I = V_{CC} or V_{EE} and V_O = V_{EE} or V_{CC}.

Fig. 6. Test circuit for measuring OFF-state leakage current



V_I = V_{CC} or V_{EE} and V_O = open circuit.

Fig. 7. Test circuit for measuring ON-state leakage current

9.2. ON resistance

Table 7. ON resistance

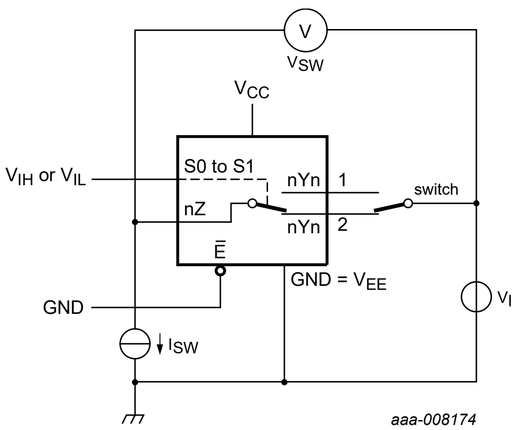
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit and graph see Fig. 8 and Fig. 9.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
$R_{ON(peak)}$	ON resistance (peak)	V_I = 0 V to V_{CC} - V_{EE}						
		V_{CC} = 1.2 V; I_{SW} = 100 µA [2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 µA	-	145	325	-	375	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 µA	-	90	200	-	235	Ω
		V_{CC} = 3.0 V to 3.6 V; I_{SW} = 1000 µA	-	80	180	-	210	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 µA	-	60	135	-	160	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 µA	-	55	125	-	145	Ω
ΔR_{ON}	ON resistance mismatch between channels	V_I = 0 V to V_{CC} - V_{EE}						
		V_{CC} = 1.2 V; I_{SW} = 100 µA [2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 µA	-	5	-	-	-	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 µA	-	4	-	-	-	Ω
		V_{CC} = 3.0 V to 3.6 V; I_{SW} = 1000 µA	-	4	-	-	-	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 µA	-	3	-	-	-	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 µA	-	2	-	-	-	Ω

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
$R_{ON(rail)}$	ON resistance (rail)	V_I = GND							
		V_{CC} = 1.2 V; I_{SW} = 100 μA	[2]	-	225	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μA		-	110	235	-	270	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μA		-	70	145	-	165	Ω
		V_{CC} = 3.0 V to 3.6 V; I_{SW} = 1000 μA		-	60	130	-	150	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μA		-	45	100	-	115	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μA		-	40	85	-	100	Ω
$R_{ON(rail)}$	ON resistance (rail)	V_I = V_{CC} - V_{EE}							
		V_{CC} = 1.2 V; I_{SW} = 100 μA	[2]	-	250	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μA		-	120	320	-	370	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μA		-	75	195	-	225	Ω
		V_{CC} = 3.0 V to 3.6 V; I_{SW} = 1000 μA		-	70	175	-	205	Ω
		V_{CC} = 4.5 V; I_{SW} = 1000 μA		-	50	130	-	150	Ω
		V_{CC} = 6.0 V; I_{SW} = 1000 μA		-	45	120	-	135	Ω

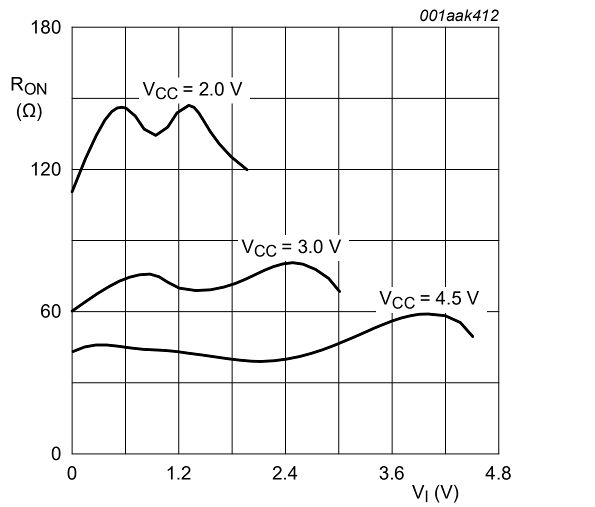
[1] Typical values are measured at T_{amb} = 25 °C.
[2] When supply voltages (V_{CC} - V_{EE}) near 1.2 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 1.2 V, only use these devices for transmitting digital signals.

9.3. On resistance test circuit and graph



$R_{ON} = V_{SW} / I_{SW}$.

Fig. 8. Test circuit for measuring R_{ON}



V_i = 0 V to V_{CC} - V_{EE}

Fig. 9. Typical R_{ON} as a function of input voltage

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Fig. 12.

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	nYn to nZ, nZ to nYn; see Fig. 10	[2]						
		V_{CC} = 1.2 V		-	25	-	-	-	ns
		V_{CC} = 2.0 V		-	9	17	-	20	ns
		V_{CC} = 2.7 V		-	6	13	-	15	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	-	5	10	-	12	ns
		V_{CC} = 4.5 V		-	4	9	-	10	ns
		V_{CC} = 6.0 V		-	3	7	-	8	ns
t_{en}	enable time	$\overline{E}$, Sn to nYn, nZ; see Fig. 11	[2]						
		V_{CC} = 1.2 V		-	190	-	-	-	ns
		V_{CC} = 2.0 V		-	65	121	-	146	ns
		V_{CC} = 2.7 V		-	48	89	-	108	ns
		V_{CC} = 3.0 V to 3.6 V; C_L = 15 pF	[3]	-	30	-	-	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	-	36	71	-	86	ns
		V_{CC} = 4.5 V		-	32	60	-	73	ns
		V_{CC} = 6.0 V		-	25	46	-	56	ns
t_{dis}	disable time	$\overline{E}$, Sn to nYn, nZ; see Fig. 11	[2]						
		V_{CC} = 1.2 V		-	125	-	-	-	ns
		V_{CC} = 2.0 V		-	43	80	-	95	ns
		V_{CC} = 2.7 V		-	33	59	-	71	ns
		V_{CC} = 3.0 V to 3.6 V; C_L = 15 pF	[3]	-	22	-	-	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	-	26	48	-	57	ns
		V_{CC} = 4.5 V		-	23	41	-	49	ns
		V_{CC} = 6.0 V		-	18	32	-	38	ns
C_{PD}	power dissipation capacitance	C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC}	[4]	-	57	-	-	-	pF

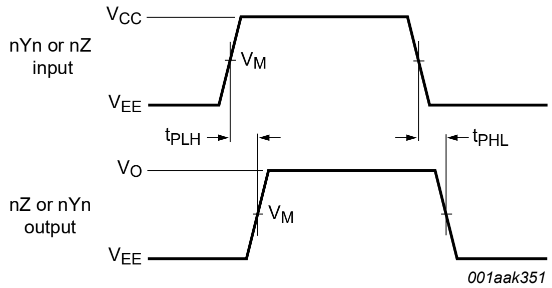
[1] All typical values are measured at T_{amb} = 25 °C.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
t_{en} is the same as t_{PZL} and t_{PZH}.
t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V).

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma((C_L + C_{sw}) \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz, f_o = output frequency in MHz
C_L = output load capacitance in pF
C_{sw} = maximum switch capacitance in pF;
V_{CC} = supply voltage in Volts
N = number of inputs switching
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

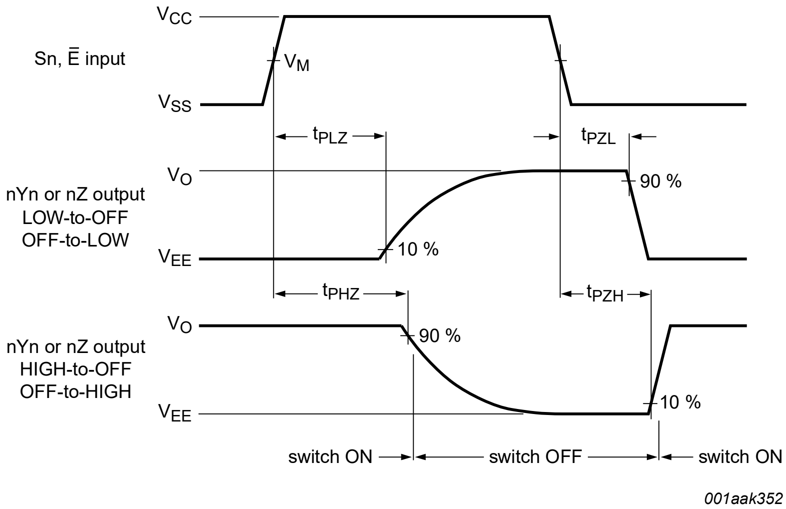
10.1. Waveforms and test circuit



Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 10. nYn, nZ to nZ, nYn propagation delays



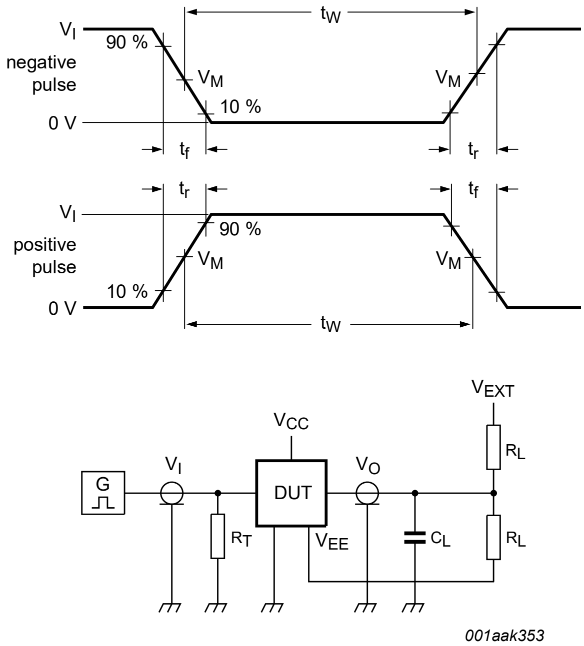
Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 11. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
< 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$
2.7 V to 3.6 V	1.5 V	1.5 V
> 3.6 V	$0.5V_{CC}$	$0.5V_{CC}$



Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 12. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V_{EXT}		
V_{CC}	V_I	t_r, t_f	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
< 2.7 V	V_{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	$2V_{CC}$
2.7 V to 3.6 V	2.7 V	≤ 6 ns	15 pF, 50 pF	1 kΩ	open	V_{EE}	$2V_{CC}$
> 3.6 V	V_{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	$2V_{CC}$

10.2. Additional dynamic parameters

Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); $t_r = t_f \leq 6.0$ ns; T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	f_i = 1 kHz; C_L = 50 pF; R_L = 10 kΩ; see Fig. 13				
		V_{CC} = 3.0 V; V_I = 2.75 V (p-p)	-	0.8	-	%
		V_{CC} = 6.0 V; V_I = 5.5 V (p-p)	-	0.4	-	%
		f_i = 10 kHz; C_L = 50 pF; R_L = 10 kΩ; see Fig. 13				
		V_{CC} = 3.0 V; V_I = 2.75 V (p-p)	-	2.4	-	%
		V_{CC} = 6.0 V; V_I = 5.5 V (p-p)	-	1.2	-	%
$f_{(-3dB)}$	-3 dB frequency response	C_L = 50 pF; R_L = 50 Ω; see Fig. 14 and Fig. 15 [1]				
		V_{CC} = 3.0 V	-	180	-	MHz
		V_{CC} = 6.0 V	-	200	-	MHz

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
α_{iso}	isolation (OFF-state)	f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω; see Fig. 16 and Fig. 17 [2]				
		V_{CC} = 3.0 V	-	-50	-	dB
		V_{CC} = 6.0 V	-	-50	-	dB
V_{ct}	crosstalk voltage	between digital inputs and switch; f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω; see Fig. 18				
		V_{CC} = 3.0 V	-	0.11	-	V
		V_{CC} = 6.0 V	-	0.12	-	V
Xtalk	crosstalk	between switches; f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω; see Fig. 19 [2]				
		V_{CC} = 3.0 V	-	-60	-	dB
		V_{CC} = 6.0 V	-	-60	-	dB

[1] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 50 Ω), adjust f_i voltage.
[2] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 600 Ω), adjust f_i voltage.

10.2.1. Test circuits

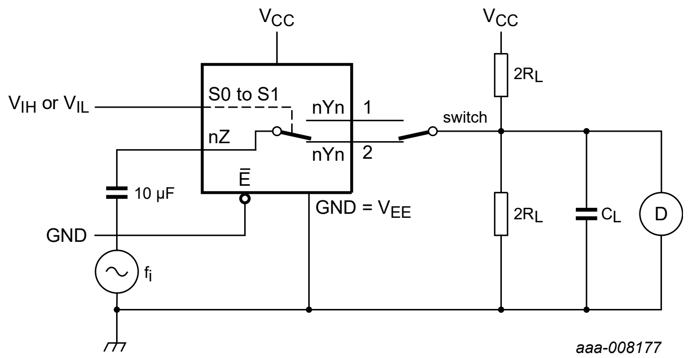


Fig. 13. Test circuit for measuring total harmonic distortion

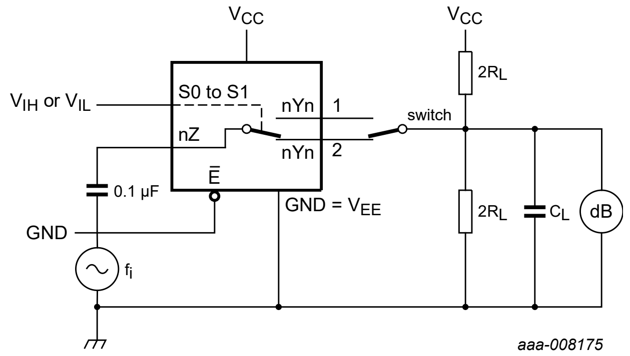
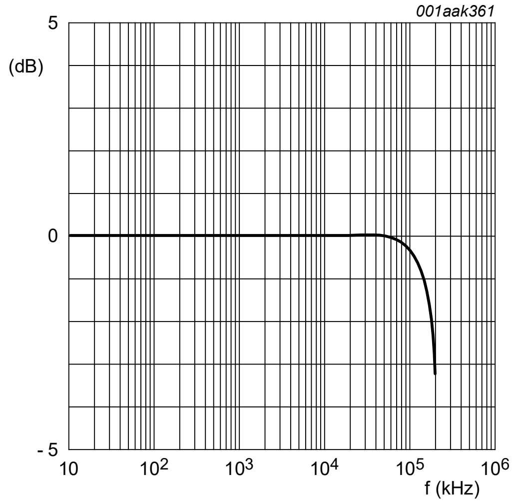


Fig. 14. Test circuit for measuring frequency response



V_{CC} = 3.0 V; GND = 0 V; V_{EE} = - 3.0 V; R_L = 50 Ω; R_{SOURCE} = 1 kΩ.

Fig. 15. Typical frequency response

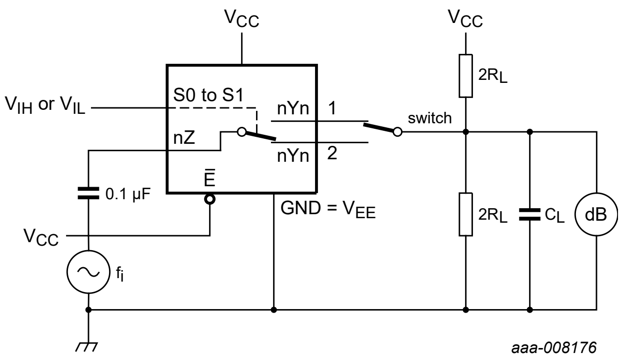
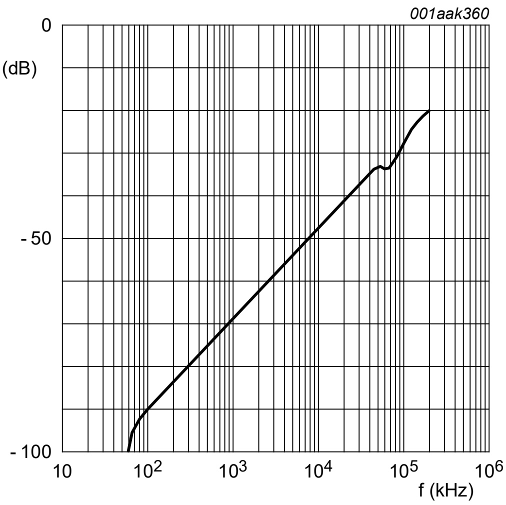
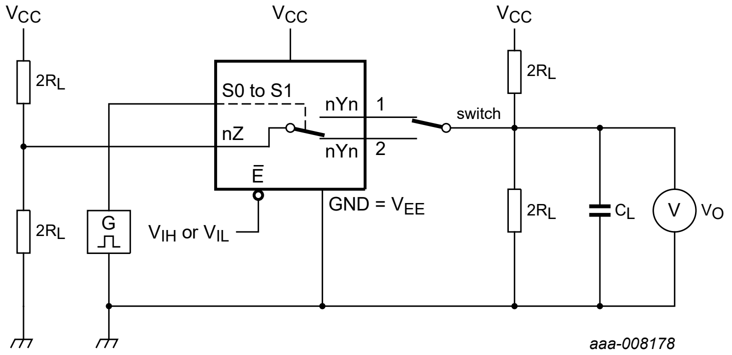


Fig. 16. Test circuit for measuring isolation (OFF-state)

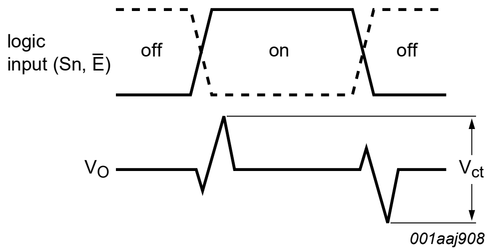


V_{CC} = 3.0 V; GND = 0 V; V_{EE} = - 3.0 V; R_L = 50 Ω; R_{SOURCE} = 1 kΩ.

Fig. 17. Typical isolation (OFF-state) as function of frequency



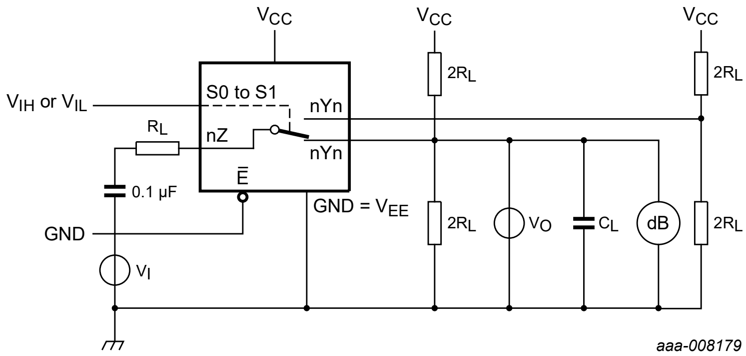
a. Test circuit



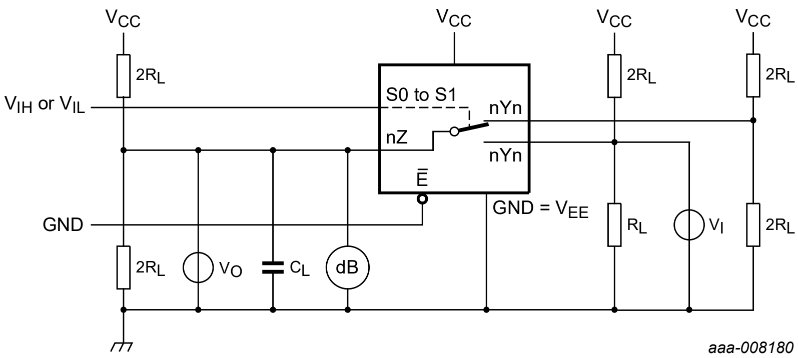
b. Input and output pulse definitions

V_I may be connected to Sn or E̅.

Fig. 18. Test circuit for measuring crosstalk voltage between digital inputs and switch



a. Switch on channel.

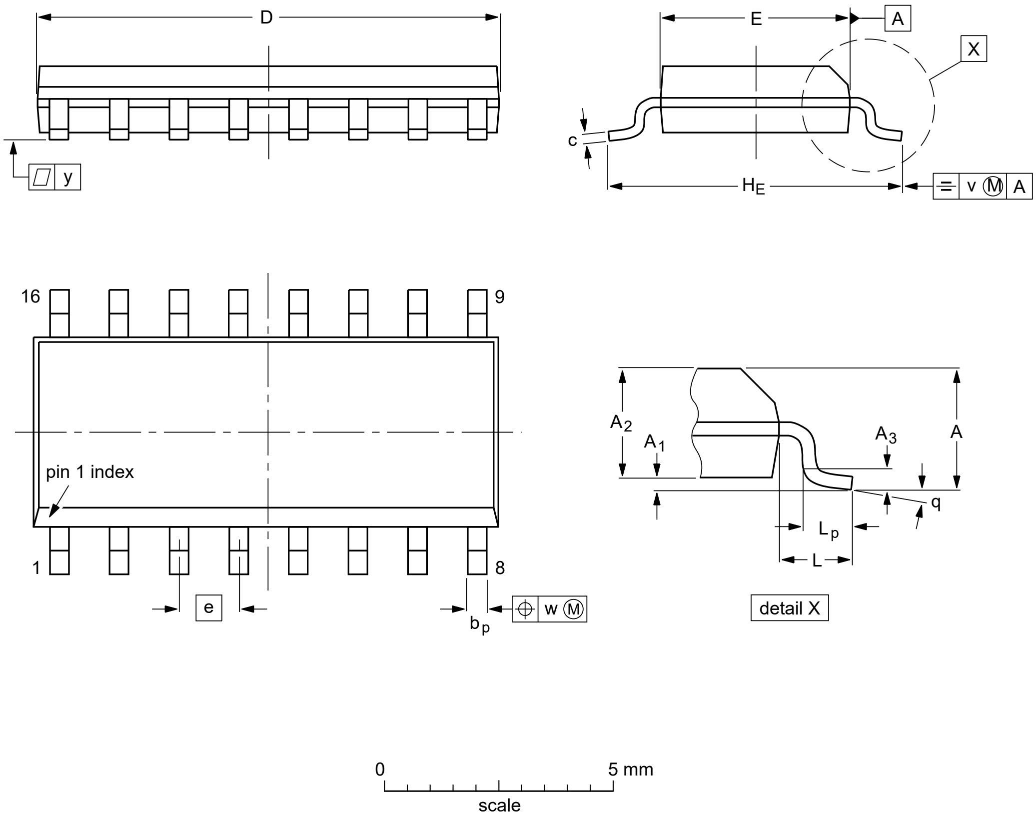


b. Switch off channel.

Fig. 19. Test circuit for measuring crosstalk between switches

11. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm **SOT109-1**



Dimensions (inch dimensions are derived from the original mm dimensions)

Unit		A	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	v	w	y	θ
mm	max	1.75	0.25			0.51	0.25	10.0	4.0		6.2		1.27				8°
	nom				0.25					1.27		1.05		0.2	0.25	0.1	
	min		0.10	1.25		0.31	0.10	9.8	3.8		5.8		0.4				0°
inches	max	0.069	0.010			0.020	0.010	0.394	0.16		0.244		0.05				8°
	nom				0.01					0.05		0.041		0.008	0.01	0.004	
	min		0.004	0.049		0.012	0.004	0.386	0.15		0.228		0.016				0°

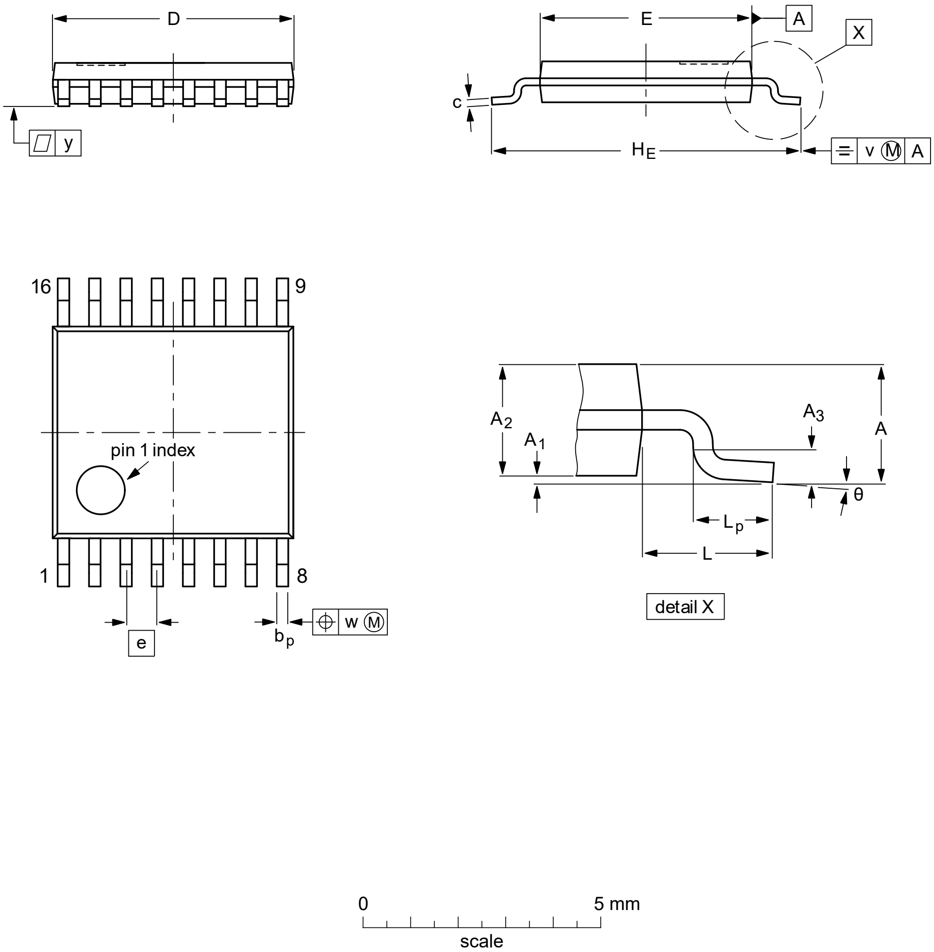
Note
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

sot109-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT109-1		MS-012				~~03-02-19~~ 23-10-27

Fig. 20. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm **SOT403-1**



Dimensions (mm are the original dimensions)

Unit		A	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	v	w	y	θ
mm	max	1.20	0.15	1.05		0.30	0.2	5.1	4.5		6.6		0.75				8°
	nom				0.25					0.65		1		0.2	0.1	0.1	
	min		0.05	0.80		0.19	0.09	4.9	4.3		6.2		0.45				0°

Note
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

sot403-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT403-1		MO-153				~~03-02-18~~ 23-10-27

Fig. 21. Package outline SOT403-1 (TSSOP16)

12. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV4052_Q100 v.5	20240329	Product data sheet	-	74LV4052_Q100 v.4
Modifications:	• Section 2: ESD specification updated according to the latest JEDEC standard. • Fig. 20 and Fig. 21: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.			
74LV4052_Q100 v.4	20210924	Product data sheet	-	74LV4052_Q100 v.3
Modifications:	• The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. • Legal texts have been adapted to the new company name where appropriate. • Section 1 and Section 2 updated. • Section 7: Derating values for P_{tot} total power dissipation updated.			
74LV4052_Q100 v.3	20151022	Product data sheet	-	74LV4052_Q100 v.2
Modifications:	• Descriptive title corrected (errata)			
74LV4052_Q100 v.2	20140915	Product data sheet	-	74LV4052_Q100 v.1
Modifications:	• Section 2: ESD protection: MIL-STD-833 changed to MIL-STD883 • Table 1: Typo in type number corrected.			
74LV4052_Q100 v.1	20130722	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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